Singular perturbation analysis of the steady state Poisson-Nernst-Planck system: applications to ion channels

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Abstract

Ion channels are proteins with a narrow hole down their middle that control a wide range of biological function by controlling the flow of spherical ions from one macroscopic region to another. Ion channels do not change their conformation on the biological time scale once they are open so they can be described by a combination of Poisson and drift diffusion (Nernst Planck) equations called PNP in biophysics. We use singular perturbation techniques to analyze the steady state PNP system for a channel with a general geometry and a piecewise constant permanent charge profile. We construct an outer solution for the case of a constant permanent charge density in three dimensions that is also a valid solution of the one dimensional system. The asymptotical currentvoltage (I-V) characteristic curve of the device (obtained by the singular perturbation analysis) is shown to be a very good approximation of the numerical I-V curve (obtained by solving the system numerically). The physical constraint of non-negative concentrations implies a unique solution, i.e., for each given applied potential there corresponds a unique electric current (relaxing this constraint yields non-physical multiple solutions for sufficiently large voltages).

1 Introduction

The prediction of ionic currents through protein channels as a function of the ionic concentration, the applied voltage and the structure of the channel is one

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of the fundamental problems in molecular biophysics [1]. On the one hand, the function of the channel depends on its microscopic geometry and content (i.e., permanent charges) which are in the atomic level, and are characterized by atomic length scales – the diameter of the channel is just a few angstroms. On the other hand, the ionic currents going through the channel are driven by macroscopic conditions. The currents are due to the applied electric potential and different ionic bath concentrations. These conditions are prescribed at a macroscopic distance away from the channel. The concentration and electric potential are unknown at the two ends of the channel. In other words, the ion channel is an atomic device. The multi-scale challenge is to understand the function of an atomic device from the prescribed macroscopic conditions.

Different channels have different geometries which can be quite complicated. Crudely speaking, the channel itself may be viewed as a pipe (cylinder) embedded in an impermeable membrane. The access region to the channel is roughly a funnel, for example, a cone. The transition geometry between the channel and the access region is smooth. It is expected that the function of the channel will depend on both its geometrical properties such as the diameter and length of the cylinder, and the geometrical properties of the access region such as the opening angle of the cone. Furthermore, nowadays, it is also possible to artificially build plastic nano-channels of roughly similar geometries and similar (although distinct) function [2, 3].

The Poisson-Nernst-Planck (PNP) equations have been proposed as the basic continuum model for ion channels [4]. PNP is also known as the drift-diffusion equations in the semiconductor literature [5], the crucial point (in both channels and semiconductors) being that the electric field is calculated from all the charge present. The electric field is not set independently of the rest of the model as it is in traditional channel models [1]. The continuum PNP system was derived from a microscopic model of Langevin trajectories in the limit of large damping and neglecting correlations of different ionic trajectories [6]. It also neglects finite size effects due to the finite size of ions. Finite size effects are approximately captured, as they are in equilibrium models of bulk solutions [7, 8, 9, 10, 11, 12, 13], by adding a suitable 'excess' term to the chemical potential [14, 15].

The dimensionless version of the time dependent PNP equations for a sys-

tem of two ionic species with opposite charges is given by

$$\frac{\lambda^2}{a^2} \Delta \phi = n - p - q,\tag{1.1}$$

$$\boldsymbol{J}^{n} = D_{n} \left(-\nabla n + n \nabla \phi \right), \tag{1.2}$$

$$\boldsymbol{J}^{p} = D_{p} \left(-\nabla p - p \nabla \phi \right), \tag{1.3}$$

$$-\nabla \cdot \mathbf{J}^{n} = \nabla \cdot \left[D_{n} \left(\nabla n - n \nabla \phi\right)\right] = \frac{\partial n}{\partial t}, \tag{1.4}$$

$$-\nabla \cdot \boldsymbol{J}^{p} = \nabla \cdot [D_{p} (\nabla p + p \nabla \phi)] = \frac{\partial p}{\partial t}, \tag{1.5}$$

where ϕ is the electric potential, n is the density of the negative charged ions, p is the density of the positive charged ions, q is the permanent charge of the channel, \mathbf{J}^n , \mathbf{J}^p are the ionic flux densities, and D_n , D_p are their diffusion coefficients. The Debye length λ is scaled with the maximum of q, and is typically a few angströms or smaller long. We scale spatial coordinates with a, where a^2 is the cross section area of the channel. This implies that all flux densities are scaled with 1/a, whereas total fluxes are scaled with a. The steady state PNP equations are obtained by setting the time derivatives $\partial n/\partial t$, $\partial p/\partial t$ to 0. The only non-dimensional parameter in the problem is $\varepsilon = \lambda/a$.

Boundary conditions for the PNP system (1.1)-(1.5) must be prescribed as well, because they drive the system out of equilibrium and produce the non-vanishing ionic fluxes. The boundary conditions are given by (see Figure 1)

$$\frac{\partial \phi}{\partial \nu} = \frac{\partial n}{\partial \nu} = \frac{\partial p}{\partial \nu} = 0, \quad \text{for } \boldsymbol{x} \in \partial \Omega_r, \tag{1.6}$$

$$\phi \to \phi_L, \quad \text{for } z \to -\infty,$$
 (1.7)

$$\phi \to \phi_R$$
, for $z \to +\infty$, (1.8)

$$n, p \to n_L = p_L, \quad \text{for } z \to -\infty,$$
 (1.9)

$$n, p \to n_R = p_R, \quad \text{for } z \to +\infty.$$
 (1.10)

where $\partial\Omega_r$ is the reflecting part of the boundary, i.e. the biological membrane, and ν is the unit normal of the boundary. The reflecting boundary condition $(1.6) \frac{\partial \phi}{\partial \nu} = 0$ approximates the "jump condition" of the electric field due to the significant difference between the dielectric constants in water and membrane. Furthermore, a reflecting boundary condition usually means the no-flux condition, e.g., $\mathbf{J}^n \cdot \nu = \mathbf{J}^p \cdot \nu = 0$. At the boundary $\frac{\partial \phi}{\partial \nu} = 0$, and equations (1.2)-(1.3) show that the no-flux boundary condition is equivalent to (1.6).

The recent mathematical analysis of the PNP system applied to channels

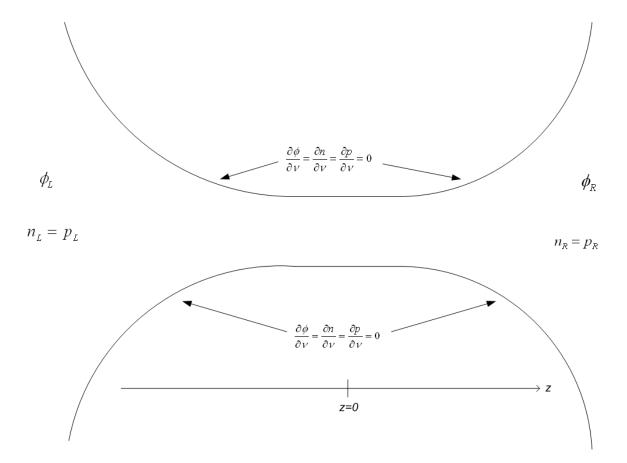


Figure 1: The ion channel geometry and boundary conditions: z measures distance symmetrically through the channel from the left bath to the right bath. The membrane walls are both flux free and electrically insulating to leading order.

[16, 17, 18] focuses on a one dimensional version of the PNP system

$$\varepsilon^2 \frac{d^2 \phi}{dz^2} = n - p - q,\tag{1.11}$$

$$\frac{dn}{dz} - n\frac{d\phi}{dz} = -J^n/D_n,\tag{1.12}$$

$$\frac{dp}{dz} + p\frac{d\phi}{dz} = -J^p/D_p,\tag{1.13}$$

with boundary conditions prescribed at the two ends of the channel, J^n , J^p are the total fluxes which are unknown, and $\varepsilon \ll 1$. However, the one-dimensional model incorporates some conceptual failures. The boundary conditions in the one-dimensional model (1.11)-(1.13) are prescribed at the two ends of the channel. Notwithstanding, the actual values of the potential and concentrations are unknown there, and are only known at a macroscopic distance away from the channel. Furthermore, as stated above, the one-dimensional model cannot capture any geometrical effects.

Nonner and Eisenberg [19] suggested the following one dimensional approximation of the three dimensional PNP system (aka the slowly varying approximation, see also [20, chapter 2, pp. 14-24])

$$\frac{\varepsilon^2}{A(z)}\frac{d}{dz}\left(A(z)\frac{d\phi}{dz}\right) = n - p - q,\tag{1.14}$$

$$A(z)\left[\frac{dn}{dz} - n\frac{d\phi}{dz}\right] = -J^n/D_n, \qquad (1.15)$$

$$A(z)\left[\frac{dp}{dz} + p\frac{d\phi}{dz}\right] = -J^p/D_p,$$
(1.16)

where J^n and J^p are once again the total fluxes. The function A(z) represents the surface area of equipotential shells. The area function A(z) grows indefinitely with z into the bath, such as the explicit example of [21] which we consider later:

$$A(z) = 1 + z^2, \quad -\infty < z < \infty.$$
 (1.17)

The fundamental drift-diffusion device equations of semiconductors are similar to the PNP system, and it is therefore not surprising that the classical singular perturbation analysis of semiconductors [5, 22, 23, 24] is applicable for ion channels as well. Yet, there are major differences between ion channels and semiconductors, even in the simplest modeling level, that call for important modifications. The parameter ε for semiconductors ($\sim 10^{-5}$) is much smaller than in ion channels. The geometry of an ion channel is much different than that of a semiconductor device. The microscopic size of the channel makes the effective ε to be much larger. In some cases, the two junction layers overlap without an outer zone [15], which means that ε is not a small parameter. Another difference between the two is expressed through the ratio of the doping

charge density to the carrier charge density of the bath (rather than in the "doped" region, where electroneutrality renders the ratio to be almost one). In semiconductors this ratio can be as large as $10^4 - 10^5$ [24] in favor of the doping charge density, whereas for channels the ratio is typically much smaller, and can be of the order of one.

Mathematically, in semiconductors the exact outer solutions are not of great importance, and the solution is mostly determined by the boundary layer solution in the junction region, whereas for channels, the outer solutions and boundary layers are both significant. Finally, in the channel problem there can be more than two ionic species with different valencies (e.g.,+1, +2, -1) which leads to rich behavior. For example, channels can suck up micromolar calcium, where the above mentioned ratio of permanent charge to carrier density is of order one for sodium, but 10^6 for calcium. In a finer level of modeling, it is well known that certain aspects of the behavior of channels, such as selectivity, are often explained by finite size effects [14, 15] that do not play a role in semiconductors.

Barcilon et al [16] analyzed (1.11)-(1.13) on a finite interval without permanent charge (q=0) as a classical singular perturbation problem. Liu [17, 18] recently analyzed a similar problem using the geometric singular perturbation approach. Gillespie [20] used singular perturbation analysis to explore many other cases, including a general geometry function A(z), a piecewise constant permanent charge profile q and space dependent diffusion coefficients (MD simulations suggest that the diffusion coefficient in a microscopic channel is much smaller than in the bulk [25, 26]) that are possibly different for the different ionic species.

In this paper we use singular perturbation techniques to analyze the steady state PNP system for a channel with a general geometry and a piecewise constant permanent charge profile. Using a suitable transformation, we convert the one dimensional system (1.14)-(1.16) to (1.11)-(1.13) with an additional geometry factor appearing only in the Poisson equation. We construct an outer solution for the case of a constant permanent charge density in three dimensions that also holds as the solution of the one dimensional system. Matching the boundary layer solution and the outer solution at the junction (the discontinuity point of the permanent charge) is possible without solving the boundary layer (Poisson-Boltzmann) equations explicitly. We focus on the case of two ionic species in a charged channel and later on the specific geometry (1.17). The asymptotical current-voltage (I-V) characteristic curve of the device (obtained by the singular perturbation analysis) is shown to be a very good approximation of the numerical I-V curve (obtained by solving the system (1.14)-(1.16) numerically). The physical constraint of non-negative concentrations implies a unique solution, i.e., for each given applied potential there corresponds a unique electric current (relaxing this constraint yields nonphysical multiple solutions for sufficiently large voltages). We bring attention here to Gillespie's doctoral thesis [20] some of whose main results are published here for the first time. The case of three ionic species with different valencies and different diffusion coefficients will be considered in a future paper.

2 Outer Solution with Constant Permanent Charge Density in Three Dimensions

Consider the three dimensional steady state PNP system (1.1)-(1.5) after the linear transformation to net charge Q = n - p and total concentration C = n + p variables given by

$$\varepsilon^2 \Delta \phi = Q - q,\tag{2.1}$$

$$\nabla \cdot [\nabla Q - C \nabla \phi] = 0, \tag{2.2}$$

$$\nabla \cdot [\nabla C - Q\nabla \phi] = 0. \tag{2.3}$$

In this first paper, we assume for algebraic simplicity equal diffusion coefficients $D_n = D_p = 1$. The permanent charge density q is assumed to be piecewise constant, that is, it has constant value q_0 inside a narrow region (i.e, the channel), and vanishes elsewhere (in the two baths). All functions satisfy no-flux (homogeneous Neumann) boundary conditions on the surface of the membrane, and Dirichlet boundary (aka far field) conditions at the left and right infinities with prescribed concentration values $C \to C_L, C_R$, potential values $\phi \to \phi_L, \phi_R$ and electro-neutrality $Q \to 0$ (see eqs (1.6)-(1.10)).

We look for an outer solution of the form

$$\phi^{OUT} = \phi_0^{OUT} + \varepsilon \phi_1^{OUT} + \dots, \tag{2.4}$$

$$Q^{OUT} = Q_0^{OUT} + \varepsilon Q_1^{OUT} + \dots, \tag{2.5}$$

$$C^{OUT} = C_0^{OUT} + \varepsilon C_1^{OUT} + \dots$$
 (2.6)

Odd powers of ε are included in the expansion, because we expect the formation of boundary layers (inner solutions) at the junctions, where q is discontinuous. In this paper we calculate the leading order terms.

The leading order equations are

$$Q_0^{OUT} = q, (2.7)$$

$$\nabla \cdot \left[\nabla Q_0^{OUT} - C_0^{OUT} \nabla \phi_0^{OUT} \right] = 0, \tag{2.8}$$

$$\nabla \cdot \left[\nabla C_0^{OUT} - Q_0^{OUT} \nabla \phi_0^{OUT} \right] = 0. \tag{2.9}$$

Electro-neutrality is expressed in (2.7). Next, we show that (2.8)-(2.9) imply the relation

$$\phi_0^{OUT} = \alpha \ln(C_0^{OUT} + \alpha q) + \beta, \qquad (2.10)$$

where α and β are constants, to be later determined by matching and boundary conditions. Indeed, $Q_0^{OUT} \equiv const$, therefore $\nabla Q_0^{OUT} = 0$, and eq. (2.8) reads

$$\nabla \cdot (C_0^{OUT} \nabla \phi_0^{OUT}) = 0. \tag{2.11}$$

We verify that relation (2.10), which can also be written in the differential form

$$\nabla \phi_0^{OUT} = \frac{\alpha}{C_0^{OUT} + \alpha q} \nabla C_0^{OUT}$$
 (2.12)

satisfies (2.9). Indeed,

$$\nabla \cdot \left(\nabla C_0^{OUT} - Q_0^{OUT} \nabla \phi_0^{OUT}\right) = \nabla \cdot \left(\nabla C_0^{OUT} - q \nabla \phi_0^{OUT}\right)$$

$$= \nabla \cdot \left(\nabla C_0^{OUT} - q \frac{\alpha}{C_0^{OUT} + \alpha q} \nabla C_0^{OUT}\right)$$

$$= \nabla \cdot \left(\frac{C_0^{OUT}}{C_0^{OUT} + \alpha q} \nabla C_0^{OUT}\right)$$

$$= \frac{1}{\alpha} \nabla \cdot \left(C_0^{OUT} \nabla \phi_0^{OUT}\right) = 0, \tag{2.13}$$

by (2.11). Equation (2.12) indicates that the homogeneous Neumann boundary conditions are satisfied by C_0^{OUT} and ϕ_0^{OUT} if any linear combination of them satisfies this boundary condition.

The calculation (2.13) also shows that the constant α is the proportionality constant between the electric current $J^e = J^n - J^p$ and the diffusion current $J^d = J^n + J^p$

$$\boldsymbol{J}_{0}^{e} = -\left[\nabla Q_{0}^{OUT} - C_{0}^{OUT} \nabla \phi_{0}^{OUT}\right] = \alpha \left[\nabla C_{0}^{OUT} - Q_{0}^{OUT} \nabla \phi_{0}^{OUT}\right] = -\alpha \boldsymbol{J}_{0}^{d}. \tag{2.14}$$

Note that $Q_0^{OUT} \equiv const$, consequently (2.9) gives in the outer zone

$$\Delta(C_0^{OUT} - q\phi_0^{OUT}) = 0, (2.15)$$

that is, $C_0^{OUT} - q\phi_0^{OUT}$ is an harmonic function, for which Neumann boundary conditions are prescribed (note that $q\phi_0^{OUT}$ is physically interpreted as the energy of the capacitor, or the energy to put the doping charge q where it is with potential ϕ_0^{OUT} – this is the minimal electrostatic work needed to build the protein from a hypothetic uncharged precursor). Combining eqs (2.10) and (2.15) we conclude that

$$(C_0^{OUT} + \alpha q) - \alpha q \ln(C_0^{OUT} + \alpha q)$$
 (2.16)

is an harmonic function.

2.1 The case $q \equiv 0$, Ohm's law, and Fick's law

In the special case where there is no permanent charge, i.e., $q \equiv 0$ it is possible to find explicit current-voltage relations.

Substituting q = 0 in relations (2.10) and (2.15) gives

$$\phi_0^{OUT} = \alpha \ln C_0^{OUT} + \beta, \tag{2.17}$$

where C_0^{OUT} is a harmonic function ($\Delta C_0^{OUT} = 0$). The constants α and β are determined by the boundary conditions

$$\phi_0^{OUT} = \phi_L + \frac{\phi_L - \phi_R}{\ln C_L - \ln C_R} \left(\ln C_0^{OUT} - \ln C_L \right). \tag{2.18}$$

The absence of permanent charge simplifies the relation for the leading order electric current and diffusion current (2.14)

$$\boldsymbol{J}_0^d = \nabla C_0^{OUT}, \tag{2.19}$$

$$\boldsymbol{J}_0^e = \frac{\phi_L - \phi_R}{\ln C_L - \ln C_R} \nabla C_0^{OUT}. \tag{2.20}$$

Fick's law is depicted in eq.(2.19) stating the diffusion flux equals the gradient of the concentration. Ohm's law is rendered in eq.(2.20) showing the electric current is proportional to the applied voltage $\phi_L - \phi_R$.

The total fluxes (integrated over any cross section) depend on the specific structure, because the harmonic function determining the concentration profile is geometry dependent. We consider the example given on [21, p. 7] chosen for its mathematical simplicity as it allows a separation of variables solution. We find equivalent formulas for our variables to those given on [21, p. 8]. The example is that of a channel lying inside the hyperboloid

$$\frac{\rho^2}{\cos^2\Theta} - \frac{z^2}{\sin^2\Theta} = 1,\tag{2.21}$$

where ρ and z are cylindrical polar coordinates, and Θ parameterize the hyperboloid. Note that $\Theta = 0$ corresponds to an impermeable boundary at z = 0, $\rho > 1$ and a hole at z = 0, $\rho < 1$. Note also that the hyperboloid gives a good approximation to the funnel shape of the protein associated with the ion channel. Introducing oblate spheroidal coordinates

$$\rho = \cosh \xi \cos \eta, \quad z = \sinh \xi \sin \eta, \tag{2.22}$$

the domain lies in $-\infty < \xi < \infty$, $\Theta < \eta \le \pi/2$. Separation of variables gives the concentration

$$C_0^{OUT} = \frac{C_R - C_L}{2} \left[\frac{4}{\pi} \arctan(e^{\xi}) - 1 \right] + \frac{C_R + C_L}{2}.$$
 (2.23)

Therefore,

$$\nabla C_0^{OUT}(\xi = 0) = \frac{C_R - C_L}{\pi \sin \eta} \boldsymbol{e}_{\xi}, \qquad (2.24)$$

where e_{ξ} is a unit normal vector to constant ξ surface.

We reintroduce the length scale a, and find the total diffusion flux to be

$$J_0^d = a\pi \int_{\Theta}^{\pi/2} \frac{C_R - C_L}{\pi \sin \eta} \sin \eta \cos \eta \, d\eta = a(C_R - C_L)(1 - \sin \Theta), \qquad (2.25)$$

and the total electric current is

$$J_0^e = a \frac{\phi_L - \phi_R}{\ln C_L - \ln C_R} (C_R - C_L) (1 - \sin \Theta). \tag{2.26}$$

As mentioned earlier, the total fluxes (2.25)-(2.26) are scaled with a. When $a \to 0$, the pore shrinks and the total fluxes vanish.

The electric resistance of the channel scaled with a is

$$R = -\frac{\phi_L - \phi_R}{J_0^e} = \frac{\ln C_L - \log C_R}{a(C_L - C_R)(1 - \sin \Theta)}.$$
 (2.27)

The L'Hospital rule applied to (2.27) for the case $C_L = C_R$ implies

$$R(C_R = C_L) = \frac{1}{aC_L(1 - \sin\Theta)}.$$
 (2.28)

In such a case when the channel is scaled with a, the conductance of the channel is proportional to the concentration.

Finally, we would like to remark on the difference between electro-neutrality and equilibrium. Note that the solution (2.17) can be represented as

$$n_0 = p_0 = \frac{C_0^{OUT}}{2} \propto e^{\phi/\alpha},$$
 (2.29)

which is different from the equilibrium Boltzmann distributions

$$n \propto e^{\phi}, \quad p \propto e^{-\phi}.$$
 (2.30)

It is widely believed that away from the channel the bath may be viewed to be in equilibrium, or at least near equilibrium. Due to that belief, for example, the pair correlation function in the bath is approximated by that of equilibrium. There are good reasons supporting the equilibrium belief. First, the ion concentrations in the bath are nearly constant, and the electric field almost vanishes, as in equilibrium. Second, equilibrium is characterized by zero net flux of all ions. Indeed, as we move away a distance r from the channel, the local fluxes are attenuated as $1/r^2$. Mathematically, one can view small fluxes as a perturbation to equilibrium, and look for a near equilibrium solution. The

solutions (2.29) and (2.30) agree to leading order (in 1/r), because they both tend to constant as $r \to \infty$, but their first order 1/r correction is different. Why is (near) equilibrium violated? The mathematical explanation is that electro-neutrality takes over the problem in the form of the small parameter ε which seems to have a profound effect more than any other physics in the problem. The physical explanation is that the total current in the baths must equal the current through the channel (by conservation and/or Kirchoff's law) and that is not zero.

3 One Dimensional Approximation

The three dimensional PNP system (2.1)-(2.3) is often approximated by the one dimensional ode system [19] (aka the slowly varying approximation)

$$\frac{\varepsilon^2}{A(z)}\frac{d}{dz}\left(A(z)\frac{d\phi}{dz}\right) = Q - q,\tag{3.1}$$

$$A(z)\left[\frac{dQ}{dz} - C\frac{d\phi}{dz}\right] = -J^e,\tag{3.2}$$

$$A(z)\left[\frac{dC}{dz} - Q\frac{d\phi}{dz}\right] = -J^d,\tag{3.3}$$

where the two transport equations are already in an integrated form, and J^e , J^d are the total fluxes. The function A(z) represents the surface area of equipotential and equi-concentrations shells. The area function A(z) grows indefinitely with z into the bath, e.g.,

$$A(z) = 1 + z^2, \quad -\infty < z < \infty.$$
 (3.4)

The change of variables

$$\frac{ds}{dz} = \frac{1}{A(z)} \tag{3.5}$$

maps the infinite axis $-\infty < z < \infty$ to a finite interval given $\int_{-\infty}^{\infty} \frac{dz}{A(z)} < \infty$, and the ode system (3.1)-(3.3) to

$$\frac{\varepsilon^2}{A(z(s))^2} \frac{d^2 \phi}{ds^2} = Q - q, \tag{3.6}$$

$$\frac{dQ}{ds} - C\frac{d\phi}{ds} = -J^e,\tag{3.7}$$

$$\frac{dC}{ds} - Q\frac{d\phi}{ds} = -J^d. {3.8}$$

The geometry appears in merely a single place as a pre-factor in the Poisson equation. For example, for $A(z) = 1 + z^2$ (1.17) we have $s = \arctan z$,

 $A(z(s)) = 1 + \tan^2 s = 1/\cos^2 s$, and the Poisson equation takes the form

$$\varepsilon^2 \cos^4 s \frac{d^2 \phi}{ds^2} = Q - q, \quad -\pi/2 < s < \pi/2.$$
 (3.9)

The transformation shows that the actual length of the interval used in [16, 17] is $L = \int_{-\infty}^{\infty} \frac{dz}{A(z)}$ rather than the physical length of the channel when modeled as a cylinder. Furthermore, the transformation also changes the location of the junctions. Note that the geometry factor is multiplied by ε^2 , so it has no leading order effects, other than those mentioned above.

The ODE system (3.6)-(3.8) is a singular perturbation problem, because the small parameter ε multiplies the high order derivative. The approximate solution consists of an outer solution and inner (boundary layer) solutions that are formed at the junctions.

The three dimensional outer solution relations (2.7),(2.10),(2.16) hold for the one dimensional case as well. In particular, (2.16) reads

$$C_0^{OUT} - \alpha q \ln(C_0^{OUT} + \alpha q) = -J^d s + \gamma, \tag{3.10}$$

where γ is a constant to be determined by matching (in one dimension, an harmonic function is also a linear function).

The outer solution net charge Q_0^{OUT} is discontinuous at the junction $s=s^*$, where its value jumps from 0 to q_0 . For that reason, a boundary layer is introduced, characterized by the local variable $\xi = (s-s^*)/\varepsilon$. The boundary layer equations are

$$\frac{1}{A(z(s^* + \varepsilon\xi))^2} \frac{d^2\phi}{d\xi^2} = Q - q,$$
(3.11)

$$\frac{dQ}{d\xi} - C\frac{d\phi}{d\xi} = -\varepsilon J^e, \tag{3.12}$$

$$\frac{dC}{d\varepsilon} - Q\frac{d\phi}{d\varepsilon} = -\varepsilon J^d. \tag{3.13}$$

The fluxes are swept away to leading order, giving rise to the equilibrium Boltzmann distributions

$$n = \frac{1}{2}(C+Q) = \frac{1}{2}C_0e^{\phi-\phi_0},$$
(3.14)

$$p = \frac{1}{2}(C - Q) = \frac{1}{2}C_0e^{-(\phi - \phi_0)}, \tag{3.15}$$

where C_0 and ϕ_0 are the values of the outer concentration and potential approaching the junction from the bath, where $Q_0^{OUT} = 0$. Multiplying equations (3.14) and (3.15) yields

$$np = \frac{1}{4}(C^2 - Q^2) = \frac{1}{4}C_0^2. \tag{3.16}$$

On the other side of the junction the net charge is $Q_0^{OUT}=q_0$. The charge $Q_0^{OUT}=q_0$ forms part of the capacitance measured across the membrane containing both lipid bilayer, channel protein, and the pore through the protein. In general $Q_0^{OUT}=q_0$ will depend nonlinearly on transmembrane voltage and will appear as a nonlinear capacitance [27, 28]. Components of capacitance of this sort contribute importantly to the properties of semiconductor diodes and junctions [29]. The charge $Q_0^{OUT}=q_0$ gives the matching concentration value

$$C_q = \sqrt{C_0^2 + q_0^2} (3.17)$$

(Physical concentrations are non-negative. Moreover, eq.(2.10) (with q=0) shows that negative concentrations lead to complex electric potential). Similarly, dividing (3.14) and (3.15) gives

$$\phi_q = \phi_0 + \frac{1}{2} \ln \left(\frac{C_q + q_0}{C_q - q_0} \right). \tag{3.18}$$

Relations (3.17) and (3.18) match the two outer solutions across the junction, without solving explicitly the boundary layer equations (that turn out to be the Poisson-Boltzmann equations).

Gillespie [20] derived these formulas in a more general system where the fixed charge q and diffusion coefficients D_n and D_p are piecewise constant along z. On each segment i ($z^{(i)} < z < z^{(i+1)}$) where these functions are constants with values $q_0^{(i)}$, $D_n^{(i)}$, and $D_p^{(i)}$, the outer solutions (to leading order) on each segment are

$$C_0^{(i)}(z) - C_0^{(i)}(z^{(i)}) + q_0^{(i)} \frac{J_-^{(i)}}{J_+^{(i)}} \ln \left(\frac{C_0^{(i)}(z) - q_0^{(i)} \frac{J_-^{(i)}}{J_+^{(i)}}}{C_0^{(i)}(z^{(i)}) - q_0^{(i)} \frac{J_-^{(i)}}{J_+^{(i)}}} \right) + J_+^{(i)} \int_{z^{(i)}}^z \frac{dz'}{A(z')} = 0$$
(3.19)

and

$$\phi_0^{(i)}(z) = \phi_0^{(i)}(z^{(i)}) - \frac{J_-^{(i)}}{J_+^{(i)}} \ln \left(\frac{C_0^{(i)}(z) - q_0^{(i)} \frac{J_-^{(i)}}{J_+^{(i)}}}{C_0^{(i)}(z^{(i)}) - q_0^{(i)} \frac{J_-^{(i)}}{J_+^{(i)}}} \right)$$
(3.20)

where

$$J_{\pm}^{(i)} = \frac{J^n}{D_n^{(i)}} \pm \frac{J^p}{D_p^{(i)}}. (3.21)$$

To connect these outer solutions across each segment boundary (that is, to determine $C_0^{(i)}\left(z^{(i)}\right)$ from $C_0^{(i-1)}\left(z^{(i)}\right)$, for example),

$$C_0^{(i)}\left(z^{(i)}\right) = \sqrt{\left(C_0^{(i-1)}\left(z^{(i)}\right)\right)^2 + \left(q_0^{(i)}\right)^2 - \left(q_0^{(i-1)}\right)^2}$$
(3.22)

and

$$\phi_0^{(i)}\left(z^{(i)}\right) = \phi_0^{(i-1)}\left(z^{(i)}\right) + \frac{1}{2}\ln\left(\frac{B^{(i)}}{B^{(i-1)}}\right) \tag{3.23}$$

where

$$B^{(i)} = \frac{C_0^{(i)}(z^{(i)}) + q_0^{(i)}}{C_0^{(i)}(z^{(i)}) - q_0^{(i)}}.$$
(3.24)

4 Numerical Study

At this point we have all the ingredients to compute the current. In the case of three segments (two baths and the charged channel), one can determine the current with the following algorithm. Given a diffusion current J_0^d the concentration C_0 at the entry to the junction is calculated using (3.10) (with q=0). The matching condition (3.17) then gives the concentration at the other side of the junction, into the charged zone at both ends. Equation (3.10) is used once again, this time with $q=q_0$, and uniquely determines the value of α , which by eq.(2.14) is the ratio of the electric and diffusion currents. The electric flux is then used to calculate the potential outside the junction in the left bath (2.10), and using (3.18) into the charged zone, and once again in the right bath, resulting the value of ϕ_R . Overall, we find the potential $V=\phi_R-\phi_L$ and electric currents J_0^e as functions of the diffusion current J_0^d . The curve (V, J_0^e) is known as the I-V (current-voltage) characteristic curve of the device.

Figure 2 shows asymptotical current-voltage curves corresponding to bath concentrations $C_L=3$ and $C_R=2$, and two different permanent charge profiles: (i) q=-1 for -1 < z < 1 with $A(z)=1+z^2$ (or q=-1 for $|s|<\pi/4$ and q=0 for $\pi/4<|s|<\pi/2$), and (ii) $q\equiv 0$ (no permanent charge), where Ohm's law predicts linear I-V curve.

For the negative charged channel, the values of J_0^d do not exceed $\frac{4}{\pi}C_L$ and $-\frac{4}{\pi}C_R$, because non-physical negative concentrations are excluded. In such a case there is a single electric current for a given applied potential. If one allows non-physical negative concentrations and complex electric potential values, then 'mathematical' multiple currents may be found [18], as shown in Figure 3 for sufficiently high voltages.

Next, we compare the leading order asymptotical result with the numerical I-V curve, obtained by solving the ODE system (3.1)-(3.3) numerically with $\varepsilon = 0.0687$. Figure 4 shows an excellent agreement between the numerical and asymptotical results for concentration boundary values $C_L = 3$ and $C_R = 2$. The approximation gets poorer at very high voltages, where we enter a different asymptotical regime, as V is no longer O(1) but rather $O(1/\varepsilon)$, violating our perturbation analysis assumptions. In particular, even though the asymptotical electric current saturates to a limit value as $V \to \pm \infty$, the nu-

merical electric current grows up indefinitely. This behavior is better depicted in Figure 5 that shows the I-V curve for $C_L = 0.3$ and $C_R = 0.2$.

Finally, we compare the numerical profiles of concentration, net charge, and potential with those predicted by the leading order outer expansion. Figures 6-8 show this comparison for the negative charged channel with $C_L = 3$, $C_R = 2$, V = 0 and $\varepsilon = 0.0687$. The figures demonstrate that the outer solution is a very good approximation of the numerical solution, but for the two boundary layers where the permanent charge is discontinuous, as predicted by the above analysis. Figures 9-11 show the successful approximation when the boundary concentration values are changed to $C_L = 0.3$ and $C_R = 0.2$. The total electric current, which is the single measured output of the device, is constant, and therefore can be evaluated at a single point away from the boundary layers, where the outer and numerical solutions show an excellent agreement. In that sense, the exact boundary layer profiles are unimportant for the determination of the fluxes.

Our work shows the importance of the access regions to channel conduction. It is clear that analyses without the access region can be misleading. We expect that different types of channels will have access regions specialized for their particular evolved function. Few complete structures of channels—including access regions—are known today to evaluate this idea.

5 Acknowledgments

The work was supported in part by NIH Grant GM076013 to Robert Eisenberg. We wish to thank Chris Breward for organizing the Maths in Medicine Study Group held at Oxford University in September 2005. We would also like to thank the other participants of the study group, in particular, Jon Chapman, Peter Howell, John King, Colin Please, Giles Richardson and Tom Witelski for helpful and fun discussions.

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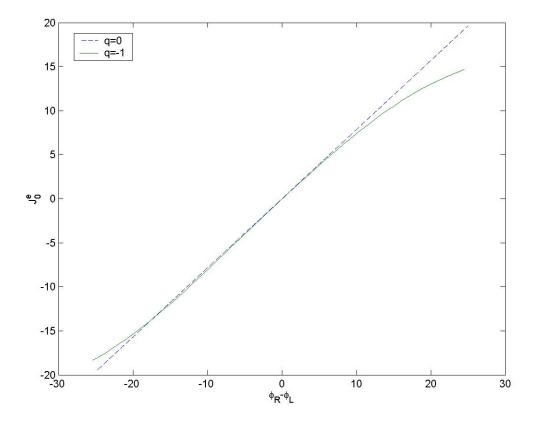


Figure 2: Current-Voltage characteristic curve: $C_L = 3$, $C_R = 2$, (i) q = -1 for -1 < z < 1 (Solid /Green) (ii) $q \equiv 0$ (Dashed / Blue). The asymptotic I-V curve is linear for the neutral channel by Ohm's law, but saturates for the charged channel. Saturation occurs at large voltages, where the asymptotic expansion is no longer valid.

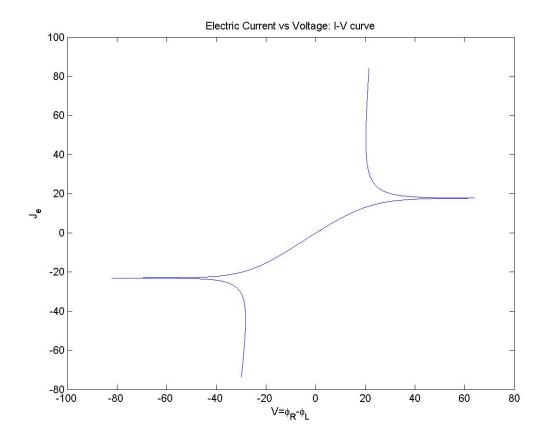


Figure 3: Non-physical Current-Voltage characteristic curve: Allowing negative concentrations gives rise to two additional branches of unbounded electric current.

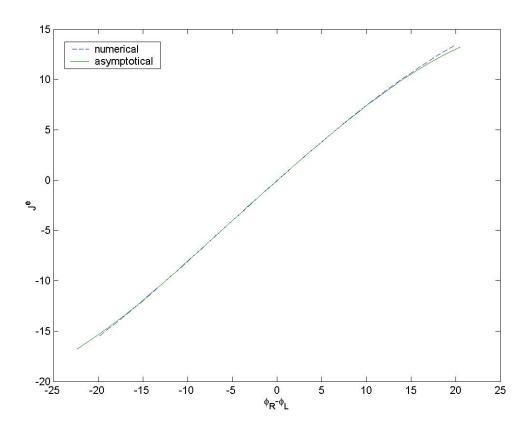


Figure 4: Current-Voltage characteristic curve: $C_L=3,\,C_R=2,\,q=-1$ for -1< z<1: (i) Numerical (Dashed / Blue), and (ii) Asymptotical (Solid / Green).

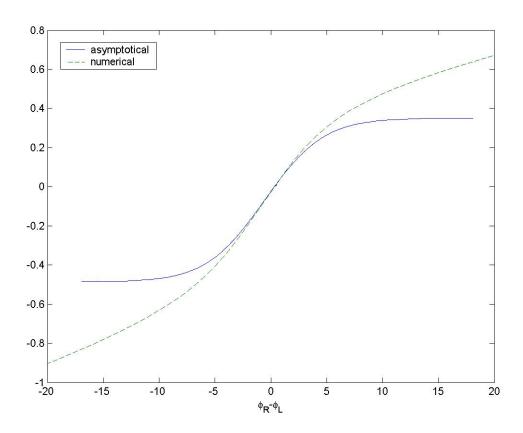


Figure 5: Current-Voltage characteristic curve: $C_L = 0.3$, $C_R = 0.2$, q = -1 for -1 < z < 1: (i) Numerical (Dash / Green), and (ii) Asymptotical (Solid / Blue). This shows the need for a correction when V becomes large.

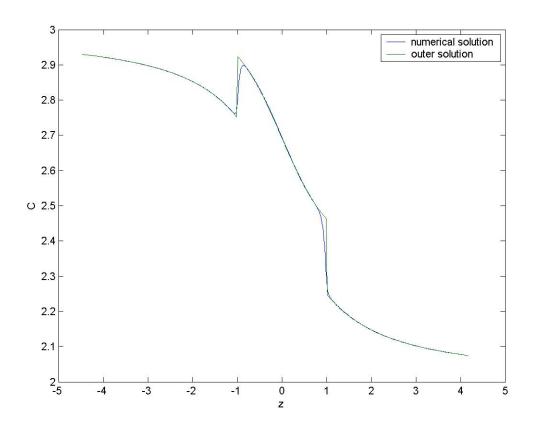


Figure 6: Concentration profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L=3,~C_R=2,~V=0,~\varepsilon=0.0687,~q=-1$ for -1 < z < 1.

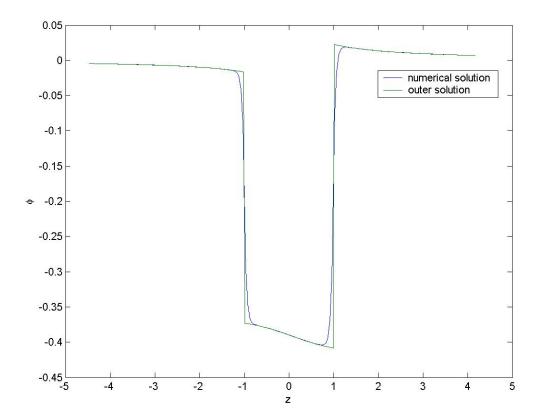


Figure 7: Potential profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L=3,\,C_R=2,\,V=0,\,\varepsilon=0.0687,\,q=-1$ for -1< z<1.

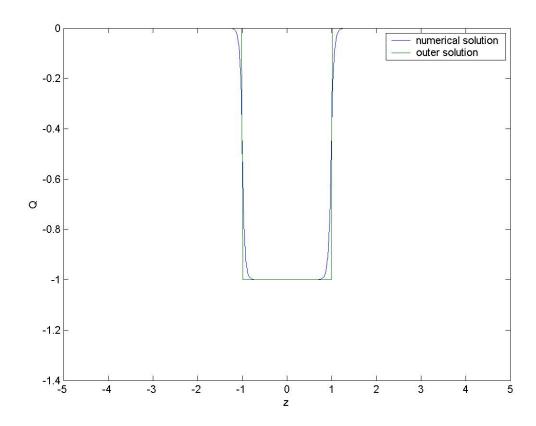


Figure 8: Net charge profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L = 3$, $C_R = 2$, V = 0, $\varepsilon = 0.0687$, q = -1 for -1 < z < 1.

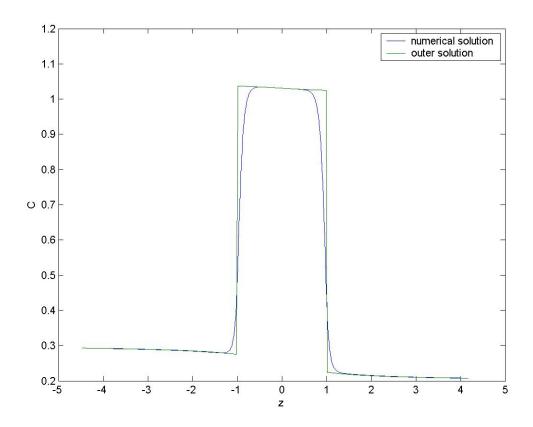


Figure 9: Concentration profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L=0.3,~C_R=0.2,~V=0,~\varepsilon=0.0687,~q=-1$ for -1 < z < 1.

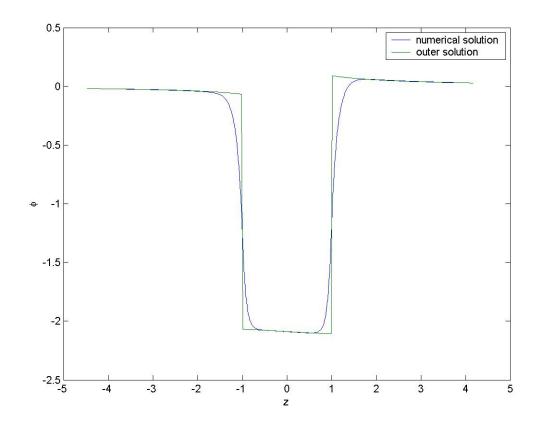


Figure 10: Potential profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L=0.3,~C_R=0.2,~V=0,~\varepsilon=0.0687,~q=-1$ for -1< z<1.

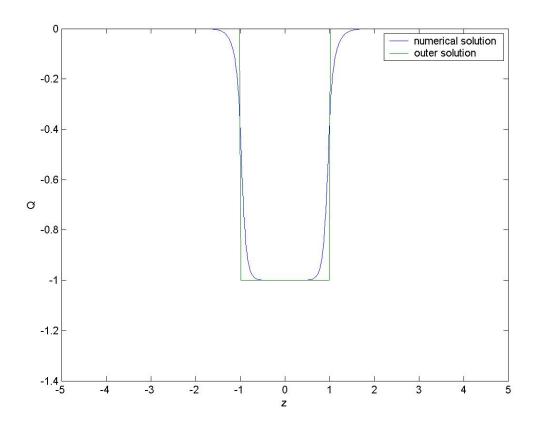


Figure 11: Net charge profile: numerical solution (Blue) vs. leading order outer solution (Green), $C_L=0.3,~C_R=0.2,~V=0,~\varepsilon=0.0687,~q=-1$ for -1 < z < 1.

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